- Power-On Reset Generator
- Automatic Reset Generation After Voltage Drop
- Low Standby Current . . . 20 μA
- Reset Output Defined When V_{CC} Exceeds 1 V
- Complementary Reset Output
- True and Complementary Reset Outputs
- Precision Threshold Voltage 4.55 V ±120 mV
- High Output Sink Capability . . . 20 mA
- Comparator Hysteresis Prevents Erratic Resets

description

The TL7757 is a supply-voltage supervisor designed for use in microcomputer and microprocessor systems. The supervisor monitors the supply voltage for undervoltage conditions. During power up, when the supply voltage, V_{CC}, attains a value approaching 1 V, the RESET output becomes active (low) to prevent undefined operation. If the supply voltage drops below threshold voltage level (V_{IT}), the RESET output goes to the active (low) level until the supply undervoltage fault condition is eliminated.

The TL7757C is characterized for operation from 0° C to 70° C. The TL7757I is characterized for operation from -40° C to 85° C.

(TOP VIEW) RESET 1 8 NC V_{CC} 2 7 NC NC 3 6 NC GND 4 5 NC

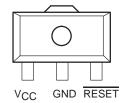
D PACKAGE

NC-No internal connection

LP PACKAGE (TOP VIEW)



PK PACKAGE (TOP VIEW)



GND is in electrical contact with the tab.

AVAILABLE OPTIONS

	PACK	AGED DEVICES		CHIP FORM
TA	SMALL OUTLINE (D)	TO-226AA (LP)	SOT-89 (PK)	(Y)
0°C to 70°C	TL7757CD	TL7757CLP	TL7757CPK	TL7757Y
-40°C to 85°C	TL7757ID	TL7757ILP	TL7757IPK	1117571

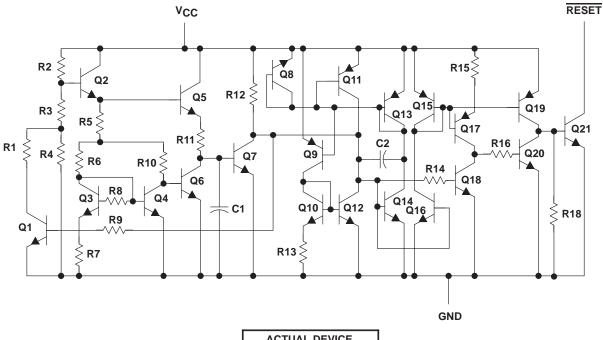
D and LP packages are available taped and reeled. Add the suffix R to device type (e.g., TL7757CDR). Chip forms are tested at 25° C.



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equivalent schematic



ACTUAL DEVICE COMPONENT COUNT				
Transistors	27			
Resistors	20			
Capacitors	2			

absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage range, V _{CC} (see Note 1)	0.3 V to 20 V
Offstate output voltage range (see Note 1)	0.3 V to 20 V
Output current, IO	30 mA
Package thermal impedance, θ_{JA} (see Notes 2 and 3): D packag	e 97°C/W
LP packa	ge 156°C/W
PK packa	nge 52°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values are with respect to network terminal ground.
 - 2. Maximum power dissipation is a function of T_J(max), $\bar{\theta}_{JA}$, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can impact reliability.
 - 3. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.



recommended operating conditions

		MIN	MAX	UNIT
Supply voltage, V _{CC}		1	7	V
High-level output voltage, VOH			15	V
Low-level output current, IOL			20	mA
Operating free air temperature Te	TL7757C	0	70	°C
Operating free-air temperature, T _A	TL7757I	-40	85	٥

electrical characteristics at specified free-air temperature

	PARAMETER	TEST CONDITIONS	.	Т			
	PARAMETER	TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
\/	Negative-going input threshold voltage at VCC		25°C	4.43	4.55	4.67	V
VIT-	Negative-going input tilleshold voltage at vCC		0°C to 70°C	4.4		4.7	V
\/. †	Hysteresis at V _{CC}		25°C	40	50	60	mV
V _{hys} †	Line Line Line Line Line Line Line Line		0°C to 70°C	30		70	IIIV
Vai	Low lovel output voltage	le 20 m/	25°C		0.4	0.8	V
VOL	Low-level output voltage	$I_{OL} = 20 \text{ mA}, V_{CC} = 4.3 \text{ V}$	0°C to 70°C			0.8	
lau	High lavel autout august	$V_{CC} = 7 \text{ V}, V_{OH} = 15 \text{ V},$	25°C			1	
ЮН	High-level output current	See Figure 1	0°C to 70°C			1	μΑ
V +	Dower up recet veltage	$R_L = 2.2 \text{ k}\Omega$	25°C		0.8	1	V
V _{res} ‡	Power-up reset voltage	V _{CC} slew rate ≤ 5 V/μs	0°C to 70°C			1.2	V
		V42V	25°C		1400	2000	
^I CC	Supply current	V _{CC} = 4.3 V	0°C to 70°C			2000	μΑ
		V _{CC} = 5.5 V	0°C to 70°C			40	

[†] This is the difference between positive-going input threshold voltage, V_{IT+}, and negative-going input threshold voltage, V_{IT-}. ‡ This is the lowest voltage at which RESET becomes active.

switching characteristics at specified free-air temperature

PARAMETER		TEST CONDITIONS	_	TL7757C				
	PARAMETER TEST CONDITIONS		T _A	MIN	TYP	MAX	UNIT	
tp	Propagation delay time, low-to-high-level	V _{CC} slew rate ≤ 5 V/μs,	25°C		3.4	5		
^t PLH	output	See Figures 2 and 3	0°C to 70°C			5	μs	
t	Propagation delay time, high-to-low-level	Soo Figures 2 and 2	25°C		2	5		
^t PHL	output	See Figures 2 and 3	0°C to 70°C			5	μs	
	Rise time	V _{CC} slew rate ≤ 5 V/μs,	25°C		0.4	1		
tr	Rise time	See Figures 2 and 3	0°C to 70°C			1	μs	
.	Fall time	See Figures 2 and 3	25°C		0.05	1		
tf	raii unie	See Figures 2 and 3	0°C to 70°C			1	μs	
	Minimum pulse duration at V _{CC} for output		25°C			5		
^t w(min)	response		0°C to 70°C			5	μs	

TL7757 **SUPPLY-VOLTAGE SUPERVISOR** AND PRECISION VOLTAGE DETECTOR

SLVS041E - SEPTEMBER 1991 - REVISED JULY 1999

electrical characteristics at specified free-air temperature

PARAMETER		TEST CONDITIONS	т.	TL7757I			UNIT
	FARAINETER	TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
\/. -	Negative-going input threshold voltage at V _{CC}		25°C	4.43	4.55	4.67	V
VIT-	Negative-going input the short voltage at VCC		–40°C to 85°C	4.4		4.7	V
\/. +	t thetereis at V		25°C	40	50	60	mV
V _{hys} †	Hysteresis at V _{CC}		–40°C to 85°C	30		70	IIIV
V/0:	Low lovel output voltage	lo 20 m/ \/oo - 4.2 \/	25°C		0.4	0.8	V
VOL	Low-level output voltage	$I_{OL} = 20 \text{ mA}, V_{CC} = 4.3 \text{ V}$	-40°C to 85°C			0.8	v
1	High level cutout current	$V_{CC} = 7 \text{ V}, V_{OH} = 15 \text{ V},$	25°C			1	
ЮН	High-level output current	See Figure 1	–40°C to 85°C			1	μΑ
V +	Dower up reget voltege	$R_L = 2.2 \text{ k}\Omega$	25°C		0.8	1	V
v _{res} ‡	Power-up reset voltage	V _{CC} slew rate ≤ 5 V/μs	–40°C to 85°C			1.2	V
		V _{CC} = 4.3 V	25°C		1400	2000	
ICC	Supply current	vCC = 4.3 v	–40°C to 85°C			2100	μΑ
		V _{CC} = 5.5 V	–40°C to 85°C			40	

[†] This is the difference between positive-going input threshold voltage, V_{IT+}, and negative-going input threshold voltage, V_{IT-}. ‡ This is the lowest voltage at which RESET becomes active.

switching characteristics at specified free-air temperature

PARAMETER		TEST CONDITIONS	т.	TL7757I			
	PARAMETER	TEST CONDITIONS T _A		MIN TYP MAX		MAX	UNIT
t	Propagation delay time, low-to-high-level output	V _{CC} slew rate ≤ 5 V/μs,	25°C		3.4	5	
tPLH	Fropagation delay time, low-to-nigh-level output	Propagation delay time, low-to-nigh-level output See Figures 2 and 3 -40°C to 85°C			5	μs	
	Decreasion delevities high to level even autout	See Figures 2 and 3	25°C		2	5	
tPHL	Propagation delay time, high-to-low-level output	See Figures 2 and 3	-40°C to 85°C			5	μs
	Dies time	ise time	25°C		0.4	1	
t _r	Nise time		See Figures 2 and 3 —40°C to 85°	–40°C to 85°C			1
	Fall time	See Figures 2 and 3	25°C		0.05	1	
tf	raii uirie	See Figures 2 and 3	-40°C to 85°C			1	μs
	Minimum pulse duration at V _{CC} for output		25°C			5	
^t w(min)	response		-40°C to 85°C			5	μs



electrical characteristics at $T_A = 25^{\circ}C$

PARAMETER		TEST CONDITIONS	TL7757Y			
		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{IT} -	Negative-going input threshold voltage at V _{CC}			4.55		V
V _{hys} †	Hysteresis at V _{CC}			50		mV
VOL	Low-level output voltage	$I_{OL} = 20 \text{ mA}, V_{CC} = 4.3 \text{ V}$		0.4		V
ІОН	High-level output current	$V_{CC} = 7 \text{ V}, V_{OH} = 15 \text{ V}, \text{See Figure 1}$				μΑ
V _{res} ‡	Power-up reset voltage	$R_L = 2.2 \text{ k}\Omega$, V _{CC} slew rate $\leq 5 \text{ V/μs}$		0.8		V
laa	Supply current	V _{CC} = 4.3 V		1400		
lcc		V _{CC} = 5.5 V				μΑ

[†] This is the difference between positive-going input threshold voltage, V_{IT+}, and negative-going input threshold voltage, V_{IT-}. ‡ This is the lowest voltage at which RESET becomes active.

switching characteristics at $T_A = 25^{\circ}C$

	PARAMETER TEST CONDITIONS		TL7757Y			
	FARAMETER	TEST CONDITIONS	MIN TYP MAX		UNIT	
tPLH	Propagation delay time, low-to-high-level output	V _{CC} slew rate ≤ 5 V/μs, See Figures 2 and 3		3.4		μs
tPHL	Propagation delay time, high-to-low-level output	See Figures 2 and 3		2		μs
t _r	Rise time	V _{CC} slew rate ≤ 5 V/μs, See Figures 2 and 3		0.4		μs
t _f	Fall time	See Figures 2 and 3		0.05		μs

PARAMETER MEASUREMENT INFORMATION

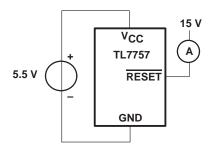
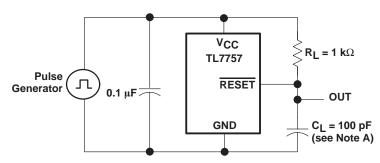


Figure 1. Test Circuit for Output Leakage Current



NOTE A: Includes jig and probe capacitance.

Figure 2. Test Circuit for RESET Output Switching Characteristics

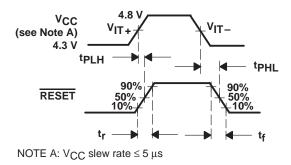


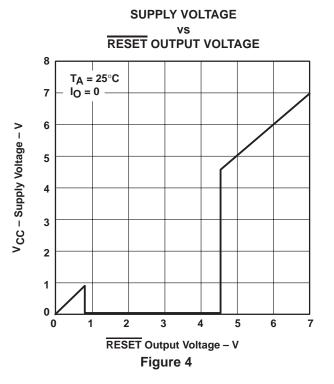
Figure 3. Switching Diagram

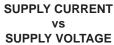


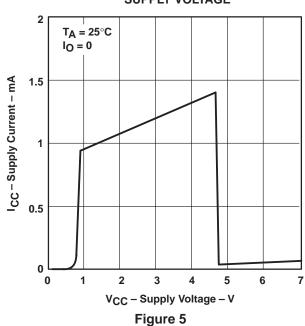
TYPICAL CHARACTERISTICS[†]

Table of Graphs

		FIGURE
Vcc	Supply voltage vs RESET output voltage	4
ICC	Supply current vs Supply voltage	5
ICC	Supply current vs Free-air temperature	6
V _{OL}	Low-level output voltage vs Low-level output current	7
VOL	Low-level output voltage vs Free-air temperature	8
loL	Output current vs Supply voltage	9
V _{IT} -	Input threshold voltage (negative-going $\ensuremath{\text{V}_{CC}}$) vs Free-air temperature	10
V _{res}	Power-up reset voltage vs Free-air temperature	11
V _{res}	Power-up reset voltage and supply voltage vs Time	12
	Propagation delay time	13

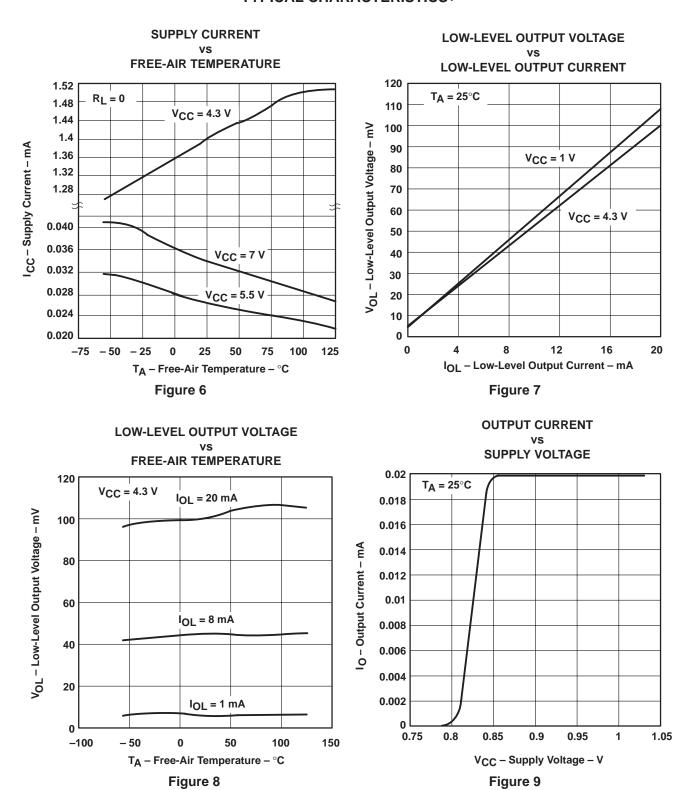






† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

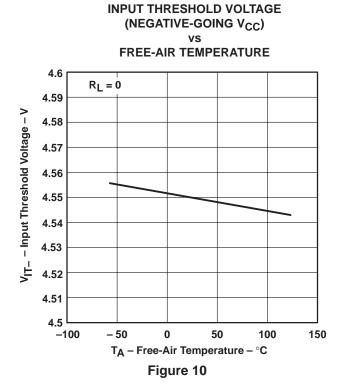
TYPICAL CHARACTERISTICS[†]

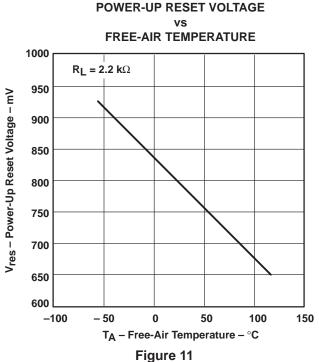


[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



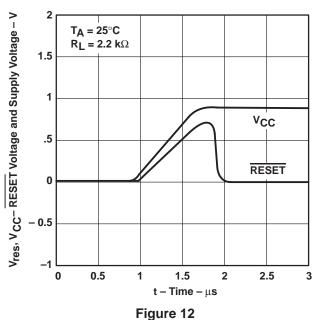
TYPICAL CHARACTERISTICS†



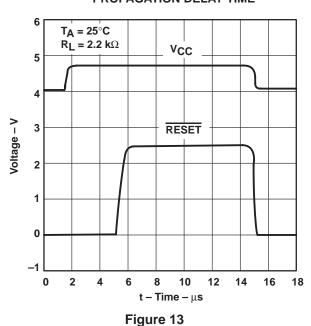


POWER-UP RESET VOLTAGE AND SUPPLY VOLTAGE ٧S

TIME



PROPAGATION DELAY TIME

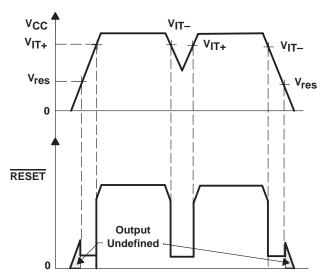


† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

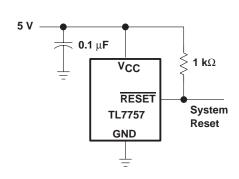


APPLICATION INFORMATION

TYPICAL TIMING DIAGRAM



TYPICAL APPLICATION DIAGRAM



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